Challenge: Point defects with strong correlations - Example: Transition - metal impurity in semiconductor Bulk bands E Band structure -TM d-states from mean field theory: Ef. (DFT, HF, QPGW) k Consider Fe replacing Al in AIN … ⇒ "Crystal field" felt by Fe: hexagonal (Csu) but approx. tetrahedral (Ta) free atom 5 ele chrons in Fest in Fest in 7 7 $\frac{T_d}{1+t_1}$ CJU $e \uparrow \uparrow \uparrow \uparrow a_i$ e 7 7 Spin 5/2, 6-fold degenorate -6 A 1 GAI 65 How can we describe this wave function? $\Psi(r_1, r_2, r_3, r_4, r_5) = \varphi(r_1) \varphi(r_2) \varphi(r_3) \varphi(r_4) \varphi(r_5)$ Needs to be antisymmetric under swapping electrons

- Write as slater determinant:

$$\frac{\psi(t_1, \dots, t_5) = \prod_{i=1}^{n} \begin{pmatrix} \phi_i(f_i) & \phi_i(f_i) & \cdots & \phi_i$$

Leal spaceRecipitral spaceWe can connect the two will Wannier orbitals• We can connect the two will Wannier orbitals• At every state k we have a Bloch function
$$y_{k(i)} = e^{ik \cdot r}$$
 $y_{k(r)}$ • Discrete Fourier transform: $\varphi_{n}(r) = \frac{1}{N} \sum_{k} e^{ik \cdot R} y_{k}(r)$ • Can include multiple bands:• Can include multiple bands: $\varphi_{ne}(r) = \frac{1}{N \times m} \sum_{k=1}^{N} \frac{1}{N \times m} \frac{1}{N$

- Next step, include Conlomb interactions
• In second quantization notation, bare Coulomb:
Hint =
$$\int \sum_{ijklogrid} V_{ijkl} C_{ij}^{i} C_{lg} C_{kg}^{i} C_{kg} C_{kg}^{i}$$

Vijkl = $\langle 0; 0_j | V_c | \Phi_k \Phi_k \rangle = \int dt. \int dr_k \Phi_i (r_i) \Phi_k^{i}(r_j) \frac{e^2}{|r_c - f_a|} \Phi_j(r_i) \Phi_k(r_a)$
=) Bulk enters Via Screening of the Gulomb
interaction in the active space
 $U = \frac{V}{E} = \frac{V}{1 + V Hir} = (1 - V Hr) V$
ERA: ind. Particle rowizability
 $PRA: ind. Particle rowizability
 $Kir(r, r', w) = \sum_{i=1}^{N} \sum_{j=1}^{N} \Psi_i(r) \Psi_i(r_j) \Psi_j(r_j) \Psi_j(r_j) \Psi_j(r_j) \Psi_i(r_j) \Psi_i($$

Hamiltonian so far:

$$H = - \sum_{ij\sigma} (t_{ij} C_{i}^{+} C_{j} + h.c.) + 1 \sum_{ijklog} U_{ijkl}^{eBM} C_{i\sigma}^{+} C_{i\sigma}^{+} C_{e\sigma}^{+} C_{e\sigma}^{-}$$

$$= Pioblem: t_{ij} comes from mean - field calculation,
already has applox Coulons interaction.
$$= Solution: Double counting correction, remove interactions
within active space
$$= For mean - field methods: density matrix element$$

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$$= for tree - Fock: H_{int}^{HF} = Z C_{i\sigma}^{+} C_{i\sigma} \sum_{ij\sigma}^{A} Pke (U_{ijk}^{eBM} - 1 U_{ikkj})$$

$$= (fint) = \sum_{ij\sigma}^{A} C_{i\sigma}^{+} C_{i\sigma} \sum_{ke}^{A} Pke (U_{eask}^{eBM} - a U_{ikki}) + V_{xc}$$

$$= find + fint = is C_{i\sigma}^{+} C_{i\sigma}^{+} \sum_{ke}^{A} Pke (U_{eask}^{eBM} - a U_{ikki}) + V_{xc}$$

$$= final + fint + i G_{i\sigma}^{A} W_{ij}$$

$$= H_{ion}^{A} + i G_{i\sigma}^{A} W_{ij}$$

$$= Final + fint + C_{i\sigma}^{A} C_{i\sigma}^{+} C_{i} = fint + i C_{i\sigma}^{A} C_{ij}$$

$$= H_{ion}^{A} + Z_{ijke}^{A} C_{ijk}^{+} C_{ijk}^{+$$$$$$

- How	40	we	solve	it?	Exact	diagonalization a.k.a	۲.
	20		_		Full	configuration interaction	

- · Let's limit ourselves to states w/ 5 electrons
- Basis states: Any slater determinant state w/ 5 electrons occupied Is label w/ binary

State	Binary label	
00000; 111112	31	
100001 011117	47	
100001;101117	55	
100001,110117	59	
;	e C	
(; ;	
11111,000007	992	
•		

• Size of matrix
$$\binom{10}{5} = \frac{10!}{5!5!} = 252$$

• Total Hilbert spare : 210 = 1024

$$e,g,: \begin{pmatrix} 10\\0 \end{pmatrix} + \begin{pmatrix} 10\\1 \end{pmatrix} + \begin{pmatrix} 10\\2 \end{pmatrix} + \cdots + \begin{pmatrix} 10\\1 \end{pmatrix} = \begin{bmatrix} 024\\1 \end{bmatrix}$$

· Now diagonalize the matrix

- Figurestates:
$$\Psi_{a} = \sum_{i=1}^{bosts} V_{ab} c_{a}^{+} C_{a}^{+} C_{o}^{+} C_{b}^{+} [0]$$

Each b corresponds to a combination of $(r_{1}, r_{1}, q_{1}, q_{1})$
in our basis
- Eigenvalues: Many body energies $\langle \Psi_{a} | H | \Psi_{b} \rangle$
- "Charge density" from IRDM: $\frac{q}{2} \langle \Psi_{a} | C_{i}^{\dagger} C_{i} | \Psi_{a} \rangle$
- dipole moments: $\langle \Psi_{a} | \frac{q}{2} \langle \Phi_{i} | \hat{\Gamma} | \Phi_{j} \rangle C_{i}^{\dagger} C_{j} | \Psi_{a} \rangle$
Results for Fe in AIN
E altern
E altern
E altern
E for Fe in AIN
E for

Summary

- Point Systems	<i>lofects</i>	are	in teres tivy	core lated	quantum
-Embeddin	s for	Pt	defects ?		
• Bulk	provides	CFS			
• Bulk	provides	scree	n'ng		
• Solve	" exactly	r" in	subspace		
• DC	importar	\t !			